

## 产 品 规 格 书

### SPECIFICATIONS FOR PRODUCT

产品类型 TYPE : Crystal

产品规格 SPEC : 25MHz/5032/20PF/20PPM

产品型号 P/N : CJ10-250002020B20

日期 DATE : 2020/08/02

<b>核准及签名</b>			<b>部门</b>
R&D APPR. SIGNATURED			DEPT.
<b>拟制</b>	<b>审核</b>	<b>批准</b>	频率器件事业部
ISSUE	CHECK	APPROVAL	
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**SMCE5032 4 pads Crystal Resonator****CJ10-250002020B20****1. Scope:**

- 1.1 This specification applies to the RoHS/SONY compliance quartz crystal unit with a frequency of 25.000MHz which will be used in crystal oscillator applications.

**2. Construction:**

- 2.1 Type of Quartz Resonator: SMCE5032 4pads

**3. Electrical Characteristics**

- |   |                      |
|---|----------------------|
| 3.1 Nominal Frequency(f):                     | 25.000MHz            |
| 3.2 Load Capacitance( $C_L$ ):                | 20pF                 |
| 3.3 Frequency Tolerance( $\Delta f/f$ ):      | $\pm 20$ ppm         |
| 3.4 Frequency Temperature Stability:          | $\pm 20$ ppm         |
| 3.5 Resonance Resistance(ohm):                | 45ohms Max           |
| 3.6 Osc mode:                                 | Fundamental mode     |
| 3.7 Shunt Capacitance( $C_0$ ):               | <2pF                 |
| 3.8 Drive Level( $D_L$ ):                     | <300 $\mu$ W         |
| 3.9 Operating Temperature Range( $T_{OPR}$ ): | -40 to + 85°C        |
| 3.10 Storage Temperature Range( $T_{STG}$ ):  | -55 to + 125°C       |
| 3.11 Insulation Resistance(IR):               | >500 M ohms          |
| 3.12 Aging( $\Delta f_A$ ):                   | $\pm 3$ ppm per Year |

## 4. Reliability Specifications

This is the quality control and quality assurance and reliability tests performance data for the RoHS/SONY compliance 25.000MHz SMCE5032 4pads crystal resonators related to the specification and approval sheet provided by JSCJ .

Standard test condition (TEMP.: 20±5°C. Relative humidity: 65±20%)

For any discrepancy in GO/NG, test will be done at TEMP.25±2°C, R.H. 65±5%.

NO.	PROCESS	SPECIFICATION	TEST METHOD
4.1	Temperature Cycle (GB/T 2423.22-2002, Method Nb)	Frequency change after test $\pm 5$ ppm. Resonance resistance change after test $\leq 10$ ohms.	10 cycles from -55°C to 125°C. Measurement taken after DUT being left at room temperature for 24±2 hours.
4.2	Low Temperature Storage (GB/T 2423.1-2001, Method Aa)	Frequency change after test $\pm 5$ ppm. Resonance resistance change after test $\leq 10$ ohms.	Spending 72 hrs at -55°C±3°C constant temperature. Measurement taken after DUT being left at room temperature for 24±2 hours.
4.3	High Temperature Storage (GB/T 2423.2-2001, Method Ba)	Frequency change after test $\pm 5$ ppm. Resonance resistance change after test $\leq 10$ ohms.	Spending 72 hrs at 125°C±3°C constant temperature. Measurement taken after DUT being left at room temperature for 24±2 hours.
4.4	Humidity (GB/T 2423.3-2006, Method Cab)	Frequency change after test $\pm 5$ ppm. Resonance resistance change after test $\leq 10$ ohms.	Spending 96 hrs at 40 °C ± 3 °C, with 93 %R.H, Then keep the DUT in dry oven at 40 ± 5 °C for 24 hour. Measurement taken after DUT being left at room temperature for 1 to 2 hours.
4.5	Vibration (GB/T 2423.10-1995, Method Fc)	Frequency change after test $\pm 5$ ppm. Resonance resistance change after test $\leq 10$ ohms.	Apply 0.75mm vibration at sweep frequency 10~500 Hz, 10 cycles in each direction of 3 axis. Measurement taken after 1 hour.
4.6	Shock (GB/T 2423.5-1995, Method Ea)	Frequency change after test $\pm 5$ ppm. Resonance resistance change after test $\leq 10$ ohms. and exhibit no visible damage.	Peak 1000m/s <sup>2</sup> , normal width 6ms half sine wave form, 3.7m/s, 3 perpendicular axis of samples, 3 cycles / direction, total 18 cycles. Measurement taken after 1 hour.
4.7	Drop (GB/T 2423.8-1995, Method Ed)	Frequency change after test $\pm 5$ ppm. Resonance resistance change after test $\leq 10$ ohms. and exhibit no visible damage.	Free drop to the steel plate with thickness of 3 mm from 1.00 m heights for 3 times.
4.8	Solderability ( IEC60068-2-58, Test Td:)	Terminals shall be covered more then 95% with solder.	Passed through the re-flow oven under the following condition. Preheat 150 to 180°C for 60 to 120sec, and soldering time for 20s ± 5s at 235°C, peak soldering time for 10s ± 1s between 240 and 250°C. There is no need to do functional test. 8-12X magnifier.
4.9	Terminal Strength (JIS-C-6429 Method 1 & 2 )	No visible damage	Mount on a glass-epoxy board (100x50x1.6mm), then bend to 2mm displacement (velocity 1mm/sec) and keep for 5 seconds. or pulling force 1.8kg for at least 60 seconds.
4.10	Resistance to Soldering Heat (IEC60068-2-58, Test Td: Table 4)	Frequency change after test $\pm 5$ ppm. Resonance resistance change after test $\leq 10$ ohms.	Passed through the re-flow oven under the following condition. Preheat 150 to 180°C for 60 to 120sec, and sodering time for 60s max at 235°C, peak soldering time for 20s max at 265°C max. Measurement taken after DUT being left at room temperature for at least 2 hours.
4.11	OTHERS		

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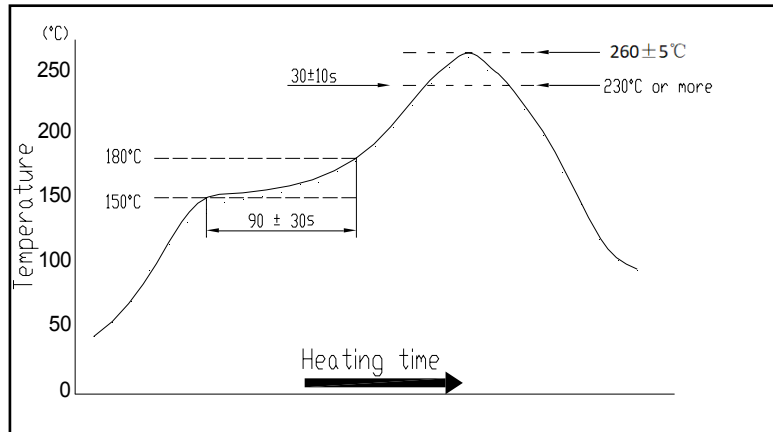
## Recommended Reflow soldering conditon

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### 5. Recommended Reflow soldering condition (SMD)

Solder profile

Peak:  $260 \pm 5^\circ\text{C}$  Soldering zone:  $230^\circ\text{C}$  or more,  $30 \pm 10\text{s}$ . Pre-heating zone 1:  $150 \sim 180^\circ\text{C}$ ,  $90 \pm 30\text{s}$

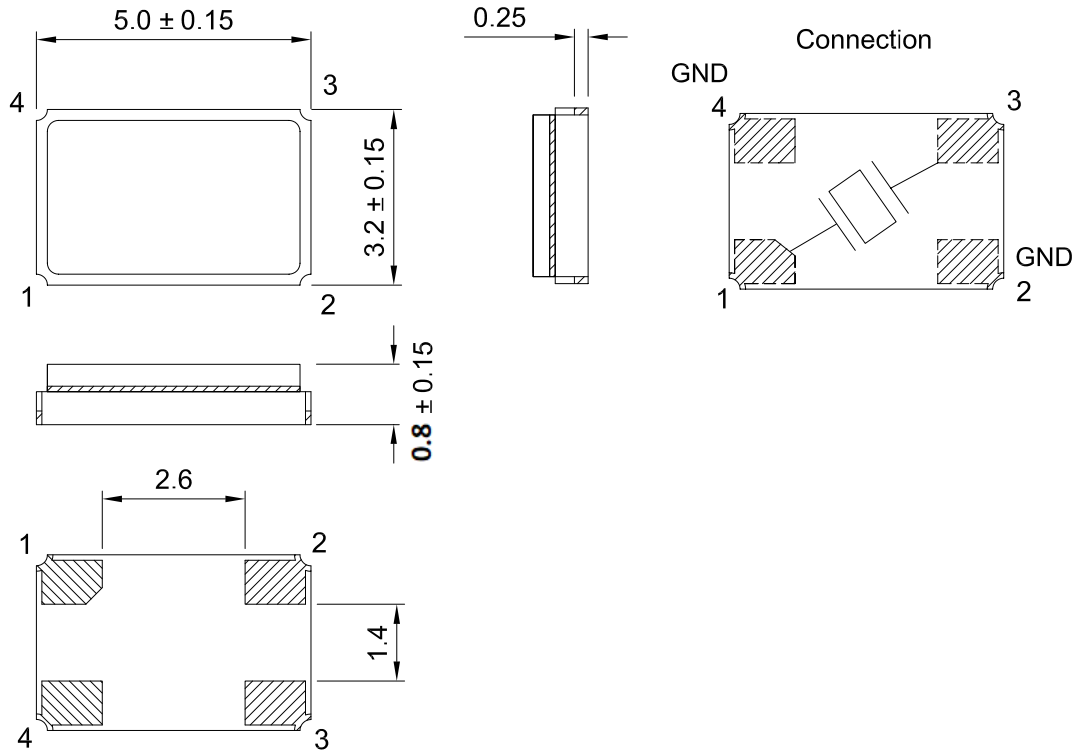


Temperature profile for reflow soldering

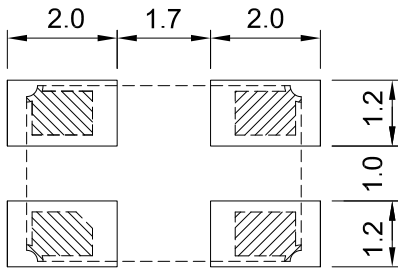
### 6. Soldering iron method

Bit temperature:  $350 \pm 10^\circ\text{C}$  Application time of soldering iron:  $3+1\text{ s}$ . For other procedures, refer to IEC 60068-2-20.

## Package Outline Dimensions

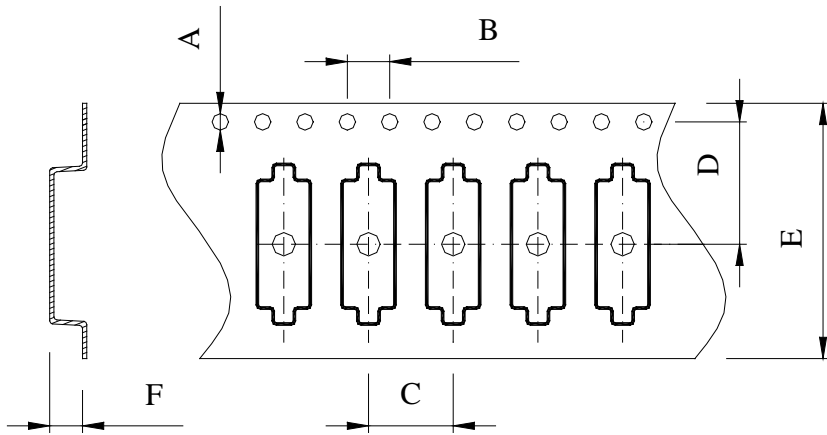


## Suggested Pad Layout



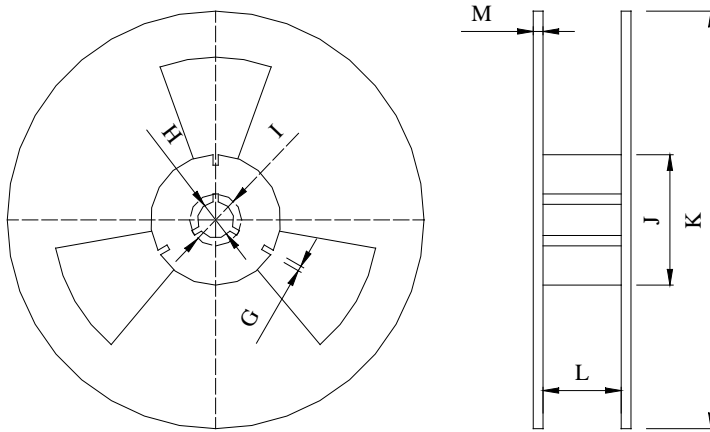
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A	B	C	D	E	F
1.5	4.0	8.0	7.5	16.0	2.0

*Reel Dimensions(unit: mm)*



G	H	I	J	K	L	M
2.3	13.5	21.6	60.0	178	16.0	1.4

**\*1000pcs/Reel**

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